# LTC2936



NOLOGY Programmable Hex Voltage Supervisor with EEPROM and Comparator Outputs DESCRIPTION

### FEATURES

- Supervises 6 Power Supplies
- I<sup>2</sup>C Adjustable UV and OV Trip Points
- Guaranteed Threshold Accuracy: ±1% (Maximum)
- I<sup>2</sup>C/SMBus Interface
- Internal EEPROM
- Six Comparator Outputs
- Fast Comparator Response Time: 7.5µs
- 256 Programmable Thresholds per Channel
- Three Range Settings per Channel
- **Two General Purpose Inputs**
- Three General Purpose Inputs/Outputs
- **Programmable Output Delays**
- Can Be Powered from 3.3V, or 3.4V to 13.9V
- 24-Lead 4mm × 5mm QFN and SSOP Packages

# **APPLICATIONS**

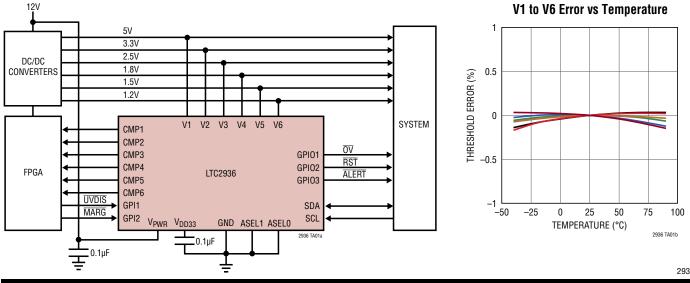
- High Availability Computer Systems
- **Network Servers**
- **Telecom Equipment**
- Data Storage

### The LTC<sup>®</sup>2936 is an EEPROM configurable voltage supervisor which can simultaneously monitor up to six power supply voltage inputs. Each voltage detector offers I<sup>2</sup>C programmable overvoltage/undervoltage thresholds in various ranges and increments and a dedicated comparator output.

Two general purpose inputs (GPI) can be configured as programmable manual reset  $(\overline{MR})$ , UV disable  $(\overline{UVDIS})$ , margin (MARG), Write Protect (WP) or auxiliary comparator (AUXC) inputs. Three general purpose pins (GPIO) can be configured for input or output operation. When configured as an input, a GPIO pin can be mapped to any other GPIO configured as output. The GPIO pins can also be configured as ALERT or fault outputs. Faults can be configured with programmable delay-on-release times. Output type and polarity are also configurable.

Status and history registers log faults and can be polled via the I<sup>2</sup>C interface. A fault snapshot is also backed up in internal EEPROM. All parameters are programmable via the I<sup>2</sup>C interface. Configuration EEPROM supports autonomous operation without additional software.

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# TYPICAL APPLICATION



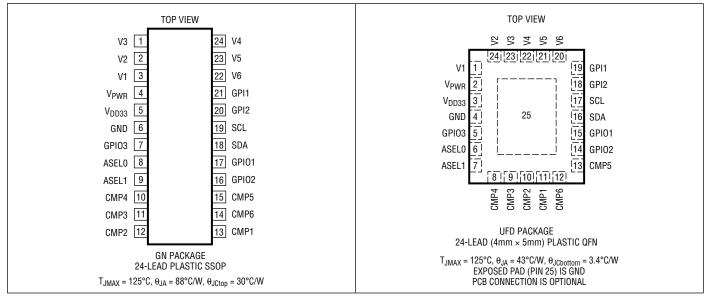
# ABSOLUTE MAXIMUM RATINGS (Notes 1, 2)

Supply Voltages	
V <sub>PWB</sub>	–0.3V to 14V
V <sub>DD33</sub>	0.3V to 3.6V
Digital Input/Output Voltages	
SDA, SCL, GPI1, GPI2	–0.3V to 6V
GPI01-GPI03, CMP1-CMP6	–0.3V to 14V
ASEL0, ASEL1	0.3V to V <sub>DD33</sub>
Analog Voltages	
V1-V6 to GND	0.3V to 6V

Operating Temperature Range	
LTC2936C	0°C to 70°C
LTC2936I	40°C to 85°C
Storage Temperature Range	–65°C to 150°C*
Maximum Junction Temperature	125°C*
Lead Temperature Range (Soldering,	10 sec)
SSOP Package	

\* See Applications Information section for detailed EEPROM derating information for junction temperatures in excess of 85°C.

# PIN CONFIGURATION



# ORDER INFORMATION

LEAD FREE FINISH	TAPE AND REEL	PART MARKING*	PACKAGE DESCRIPTION	TEMPERATURE RANGE
LTC2936CGN#PBF	LTC2936CGN#TRPBF	LTC2936GN	24-Lead Plastic SSOP	0°C to 70°C
LTC2936IGN#PBF	LTC2936IGN#TRPBF	LTC2936GN	24-Lead Plastic SSOP	-40°C to 85°C
LTC2936CUFD#PBF	LTC2936CUFD#TRPBF	2936	24-Lead (4mm $\times$ 5mm) Plastic QFN	0°C to 70°C
LTC2936IUFD#PBF	LTC2936IUFD#TRPBF	2936	24-Lead (4mm × 5mm) Plastic QFN	–40°C to 85°C

Consult LTC Marketing for parts specified with wider operating temperature ranges. \*The temperature grade is identified by a label on the shipping container. For more information on lead free part marking, go to: http://www.linear.com/leadfree/

For more information on tape and reel specifications, go to: http://www.linear.com/tapeandreel/



# **ELECTRICAL CHARACTERISTICS** The $\bullet$ denotes the specifications which apply over the full operating temperature range, otherwise specifications are at T<sub>A</sub> = 25°C and V<sub>PWR</sub> = 12V (Note 2).

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNITS
Power Supp	ly Characteristics					
V <sub>PWR</sub>	V <sub>PWR</sub> Supply Voltage Range		• 3.4		13.9	V
V <sub>DD33</sub>	V <sub>DD33</sub> Regulator Output Voltage	I <sub>VDD33</sub> = -1mA	• 3.23	3.3	3.37	V
I <sub>DD</sub>	V <sub>DD33</sub> Regulator Current Limit	V <sub>DD33</sub> = 0V	• -10			mA
V <sub>DDEXT</sub>	V <sub>DD33</sub> Supply Voltage Range	V <sub>DD33</sub> = V <sub>PWR</sub>	• 3.13	3.3	3.47	V
I <sub>PWR</sub>	V <sub>PWR</sub> Supply Current	Writing to EEPROM	•		0.7 1.5	mA mA
IVDDEXT	V <sub>DDEXT</sub> Supply Current	Writing to EEPROM	•		0.7 1.5	mA mA
Voltage Sup	ervisor Characteristics		I I			<u> </u>
V <sub>RANGE</sub>	V <i>n</i> Monitoring Range	Precision Range Low Range Medium Range	• 0.2 • 0.5 • 1		1.2 3 5.8	V
V <sub>STEP</sub>	V <i>n</i> Threshold Programming Step (LSB)	Precision Range Low Range Medium Range		4 10 20		mV
V <sub>ERR</sub>	V <i>n</i> Threshold Accuracy	Precision Range, $0.6V < Vn < 1.2V$ Precision Range, $0.2V < Vn < 0.6V$ Low Range, $1.5V < Vn < 3V$ Low Range, $0.5V < Vn < 1.5V$ Medium Range, $3V < Vn < 5.8V$ Medium Range, $1V < Vn < 3V$			±1 ±6 ±1 ±15 ±1 ±30	% mV % mV % mV
R <sub>IN</sub>	V <i>n</i> Input Impedance	Low and Medium Range and High Range	• 400	600		kΩ
I <sub>IN</sub>	V <i>n</i> Input Current	Precision Range, 1.2V Input	•		±10	nA
t <sub>RT</sub>	Vn Comparator Response Time	2 LSB of Overdrive 20 LSB of Overdrive	•	15 7.5	10	μs μs
Manual Res	et Characteristics					·
t <sub>MRI</sub>	Input Pulse Width	Active Low	• 5			μs
t <sub>MRR</sub>	Glitch Rejection			1		μs
CMP <i>n</i> Outpu	It Characteristics					<u>.                                    </u>
V <sub>OL</sub>	Low Output Voltage	I <sub>SINK</sub> = 3mA			0.4	V
I <sub>LEAK</sub>	Leakage Current	V <sub>CMP</sub> = 13.9V	•		±2	μA
I <sub>PU</sub>	Internal Pull-up Current	V <sub>CMP</sub> = 2V	• -5	-15	-30	μA
GPI <i>n</i> Chara	cteristics					<u> </u>
V <sub>ITH</sub>	Input Threshold Voltage		• 0.6	1	1.4	V
I <sub>LEAK</sub>	Leakage Current	V <sub>GPI</sub> = 6V	•		±2	μA
I <sub>PU</sub>	Internal Pull-up Current	V <sub>GPI</sub> = 2V	• -5	-15	-30	μA
Auxiliary Co	mparator Characteristics					
V <sub>ACIN</sub>	Input Threshold Voltage		• 0.49	0.5	0.51	V
I <sub>ACIN</sub>	Input Current	Input Voltage = 0.5V	•		±10	nA
t <sub>ACRT</sub>	Response time	40mV Overdrive		25		μs
GPIO <i>n</i> Char	acteristics					
V <sub>OL</sub>	Low Output Voltage	I <sub>SINK</sub> = 3mA	•		0.4	V
V <sub>ITH</sub>	Input Threshold Voltage		• 0.6	1	1.4	V
I <sub>LEAK</sub>	Leakage Current	V <sub>GPI0</sub> = 13.9V	•		±2	μA
I <sub>PU</sub>	Internal Pull-up Current	V <sub>GPI0</sub> = 2V	• -5	-15	-30	μA



# **ELECTRICAL CHARACTERISTICS** The $\bullet$ denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^{\circ}$ C and $V_{PWR} = 12V$ (Note 2).

SYMBOL	PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS
t <sub>DRO</sub>	Programmable Output Delay-On-Release GPI01_DELAY_ON_RELEASE, GPI02_DELAY_ON_RELEASE and GPI03_DELAY_ON_RELEASE	000b 001b 010b 011b 100b 101b 110b		1 4.5 17.9 35.8 143.3 286.6	0.001 1.6 6.4 25.6 51.2 204.8 409.6	0.050 2.1 8.3 33.3 66.6 266.3 532.6	ms ms ms ms ms ms
EEPROM Chai	venterietien	111b	•	1146	1638	2130	ms
Retention	Retention (Notes 5, 6)			10			Years
Endurance	Endurance (Notes 5, 6)			10,000			Cycles
	Fault Storage Time (Note 4)	Backup Fault Storage Operation		10,000	10		
t <sub>EEFS</sub>	Programming Time	I <sup>2</sup> C NAK's During STORE_USER Operation	_		100		ms
t <sub>EEPR</sub>	Restore Time	RESTORE_USER Command			100		ms
t <sub>EERU</sub> Digital Inputs					I		ms
	High Level Input Voltage	1		2.0			V
	Low Level Input Voltage			2.0		0.8	V
	Input Hysteresis (Note 4)				40	0.0	mV
V <sub>HYST</sub>	Input Leakage Current	SCL, SDA = GND to 5.5V		-1	40	1	μΑ
I <sub>LEAK</sub> Digital Output		302, 30A = 0.00 10 3.37	•	-1		I	μΑ
	Digital Output Low Voltage	I <sub>SINK</sub> = 3mA		1		0.4	V
	ASELO, ASEL1	ISINK = SIIA	•			0.4	<u> </u>
	Input High Threshold Voltage					V	V
VIН						V <sub>DD33</sub> – 0.4	v
V <sub>IL</sub>	Input Low Threshold Voltage		•	0.4			V
I <sub>IH,IL</sub>	High, Low Input Current	ASEL <i>n</i> = 0, V <sub>DD33</sub>	•	-20		20	μA
I <sub>FLOAT</sub>	High Z Input Current	0.5V< ASEL <i>n</i> < V <sub>DD33</sub> – 0.5V	•	-10		10	μA
	ning Characteristics (Note 3)	1		1			<u>.</u>
f <sub>SCL</sub>	Serial Clock Frequency			10		400	kHz
t <sub>LOW</sub>	Serial Clock Low Period			1.3			μs
t <sub>HIGH</sub>	Serial Clock High Period		•	0.6			μs
t <sub>BUF</sub>	Bus Free Time Between Stop and Start		•	1.3			μs
t <sub>HD,STA</sub>	Start Condition Hold Time			600			ns
t <sub>SU,STA</sub>	Start Condition Setup Time		•	600			ns
t <sub>SU,STO</sub>	Stop Condition Setup Time			600			ns
t <sub>HD,DAT</sub>	Data Hold Time	LTC2936 Receiving Data	•	0			ns
-,		LTC2936 Transmitting Data	•	300			ns
t <sub>SU,DAT</sub>	Data Setup Time		•	100			ns
t <sub>SP</sub>	Pulse Width of Spike Suppressed				100		ns
t <sub>timeout_bus</sub>	Time Allowed to Complete Any PMBus Command After Which Time SDA Will Be Released and Command Terminated				32		ms

# **ELECTRICAL CHARACTERISTICS**

**Note 1:** Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime. The LTC2936 is tested with  $T_A = T_{CASE}$ .

**Note 2:** All currents into device pins are positive; all currents out of device pins are negative. All voltages are referenced to GND unless otherwise specified.

**Note 3:** Maximum capacitive load,  $C_B$ , for SCL and SDA is 400pF. Data and clock rise time  $(t_r)$  and fall time  $(t_f)$  are:

 $(20 + 0.1 \cdot C_B)$  (ns) < t<sub>r</sub> < 300ns, and

 $(20 + 0.1 \bullet C_B) (ns) < t_f < 300 ns$ 

 $C_B$  = capacitance of one bus line in pF. SCL and SDA external pull-up voltage,  $V_{10},$  is 3V  $< V_{10} <$  5.5V.

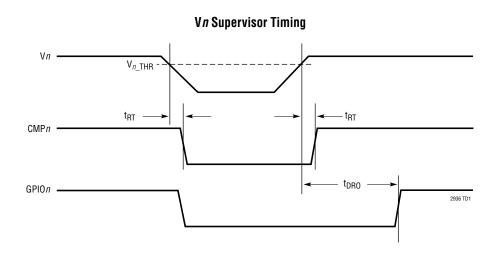
Note 4: Guaranteed by design, not directly tested.

**Note 5:** EEPROM endurance and retention are guaranteed by design, characterization and correlation with statistical process controls. The minimum retention specification applies for devices whose EEPROM has been cycled less than the minimum endurance specification.

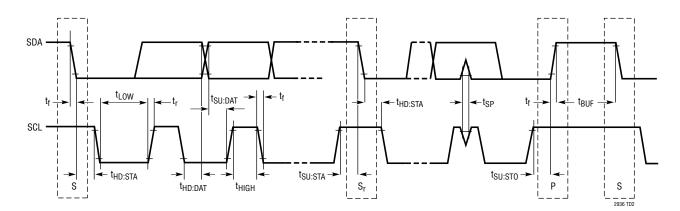
**Note 6:** EEPROM endurance and retention will be degraded when  $T_J > 85^{\circ}C$ .



# TIMING DIAGRAMS



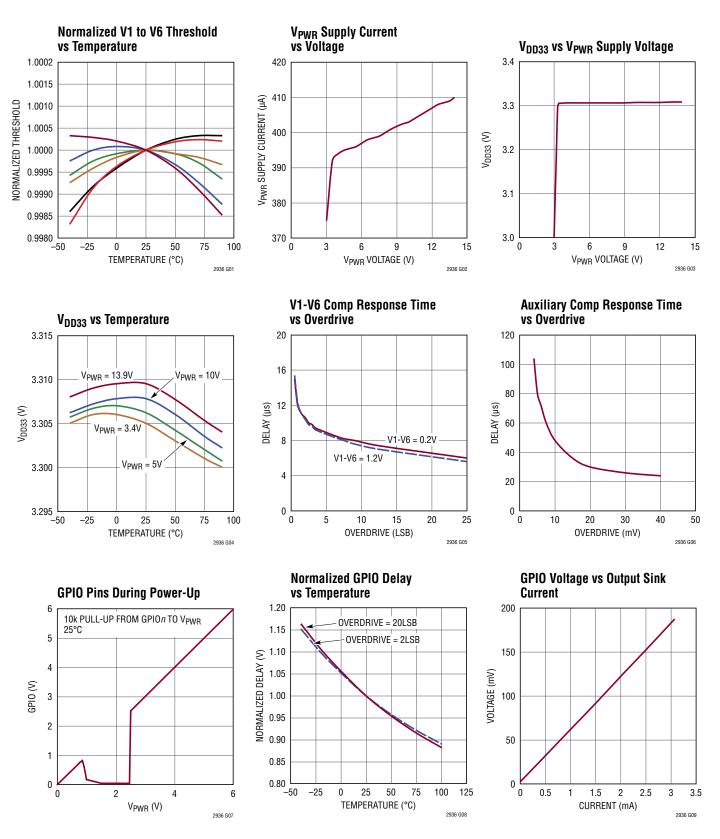
I<sup>2</sup>C Timing





2936f

### **TYPICAL PERFORMANCE CHARACTERISTICS**



**LINEAR** TECHNOLOGY

# PIN FUNCTIONS

**ASELO, ASEL1:**  $I^{2}C$  Bus Address Select Inputs. Can be connected to ground,  $V_{DD33}$  or can be left unconnected to select 1 out of 9 addresses.

**CMP1-CMP6:** Comparator Open-Drain Outputs. These pins assert low in response to a user-programmable combination of UV and OV conditions on the associated channels. Each output has a  $15\mu$ A pull-up to V<sub>DD33</sub>.

**Exposed Pad (QFN Package Only):** Ground. The exposed pad may be left open or connected to device ground.

GND: Ground.

**GPI1**, **GPI2**: General Purpose Inputs. Configurable as one of five possibilities (no duplication):

- Manual reset ( $\overline{\text{MR}}$ ) input, active low, 15µA pull-up to  $V_{\text{DD33}}$
- UV disable (UVDIS), active low, 15µA pull-up to V<sub>DD33</sub>. Outputs ignore UV faults.
- Margin (MARG), active low, 15µA pull-up to V<sub>DD33</sub>. Outputs ignore both UV and OV faults.
- Write Protect ( $\overline{WP}$ ), active low, 15µA pull-up to V<sub>DD33</sub>. I<sup>2</sup>C write commands are ignored.
- Hi-Z Auxiliary Comparator (AUXC) Input. Programmable polarity.

**GPI01, GPI02, GPI03:** General Purpose Input/Output. Each GPI0 is configurable as either input, open-drain output, or weak pull-up output. Output polarity is programmable. When configured as outputs, these pins respond to selectable UV conditions, OV conditions, MR, auxiliary comparator output, or other input-configured GPIO*n* with programmable delay-on-release. These pins can also be configured as ALERT per SMBus standard. When configured as inputs, each pin can be mapped to any other output. These pins have an optional 15µA pullup to V<sub>DD33</sub>. Unused GPIO pins should be tied to V<sub>DD33</sub> or have their pull-up enabled.

**SCL:** I<sup>2</sup>C Serial Clock (400kHz Maximum). Needs external pull-up resistor.

**SDA**: I<sup>2</sup>C Serial Data. Needs external pull-up resistor.

**V1-V6:** Voltage Supervisor Input. Programmable thresholds from 0.2V to 1.2V in 4mV increments (precision range), from 0.5V to 3V in 10mV increments (low range) or from 1V to 5.8V in 20mV increments (medium range). See the Applications Information section for information on unused channels.

 $V_{DD33}$ : 3.3V Internal Regulator Output. A 100nF capacitor to ground is required. The internal regulator can be disabled by connecting  $V_{PWR}$  to  $V_{DD33}$  and operating from an external 3.3V supply.

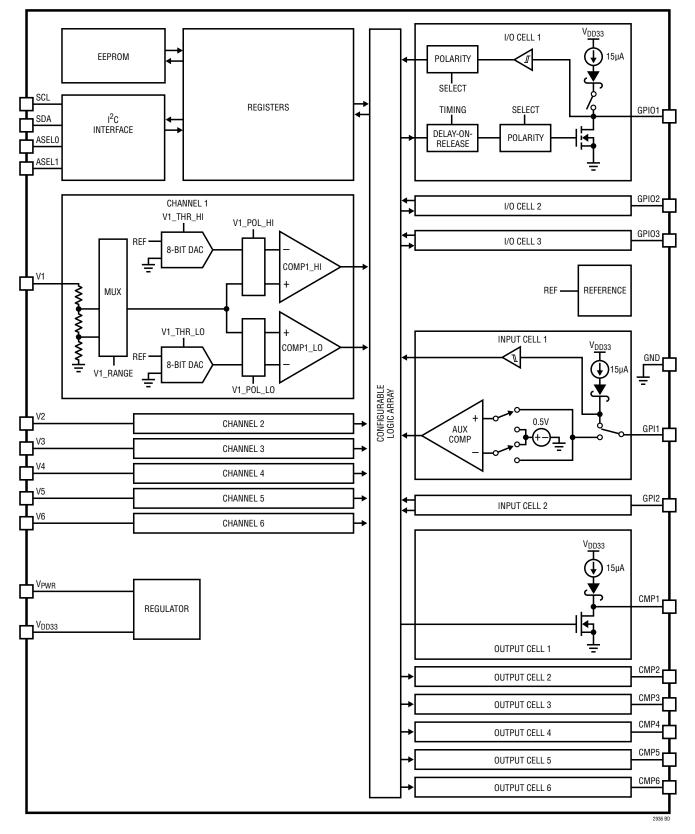
**V**<sub>PWR</sub>: Power Supply Input (Internal Regulator Input). Power supply range is 3.4V to 13.9V. Bypass this pin to ground with a 100nF (or greater) capacitor. The internal regulator can be disabled by connecting V<sub>PWR</sub> to V<sub>DD33</sub> and operating from an external 3.3V supply.

PIN NAME	PIN TYPE	PIN (SSOP)	PIN (QFN)		
V3	IN	1	23		
V2	IN	2	24		
V1	IN	3	1		
V <sub>PWR</sub>	IN	4	2		
V <sub>DD33</sub>	OUT/IN	5	3		
GND	GND	6	4, 25		
GPI03	IN/OUT	7	5		
ASEL0	IN	8	6		
ASEL1	IN	9	7		
CMP4	OUT	10	8		
CMP3	OUT	11	9		
CMP2	OUT	12	10		
CMP1	OUT	13	11		
CMP6	OUT	14	12		
CMP5	OUT	15	13		
GPI02	IN/OUT	16	14		
GPI01	IN/OUT	17	15		
SDA	IN/OUT	18	16		
SCL	IN	19	17		
GPI2	IN	20	18		
GPI1	IN	21	19		
V6	IN	22	20		
V5	IN	23	21		
V4	IN	24	22		



29361

# **BLOCK DIAGRAM**



<sup>2936f</sup>



The LTC2936 can perform the following operations:

- Accept I<sup>2</sup>C bus programming commands.
- Simultaneously monitor up to six inputs with respect to I<sup>2</sup>C bus programmed fault limits and assert/de-assert the associated CMP*n* outputs in response to OV and/ or UV faults.
- Configure and monitor for OV/UV faults using two independent comparators per channel.
- Configure two general purpose inputs as manual reset (MR), undervoltage disable (UVDIS), margin (MARG), write protect (WP) or auxiliary comparator (AUXC) inputs.
- Configure three general purpose inputs/outputs (GPIO*n*) to output faults, inputs from GPI*n* or from other GPIO*n*.
- Independently select each general purpose output polarity and type (open-drain or weak pull-up).
- Independently select each general purpose output response delay-on-release (with respect to the moment its condition is internally cleared).
- Generate interrupt (ALERT) signals in response to any voltage faults, as well as the logic state of the inputs.
- Store register contents to EEPROM.
- Store voltage and timing fault history to EEPROM.
- Restore EEPROM contents into the operating memory, by I<sup>2</sup>C command and at power-up.
- Report voltage fault status and history.
- Hardware and/or software write-protect the operating memory.

### THRESHOLD ACCURACY

The LTC2936  $\pm 1\%$  threshold accuracy specification improves the reliability of the system over supervisors with wider threshold tolerances. A less accurate voltage supervisor increases the required system voltage margin. This in turn increases the probability of system malfunction.

Consider a  $5V \pm 10\%$  supply: it may vary between 4.5V and 5.5V and the circuitry powered by it must operate reliably within this band. An ideal, perfectly accurate supervisor would generate a reset at exactly 4.5V. The LTC2936 threshold varies  $\pm 1\%$  around the nominal threshold voltage, in the medium range, if the selected value is greater than 3V. The reset threshold band and the power supply tolerance bands should not overlap, in order to prevent false alarms when the power supply actually meets its specified tolerance band (see Figure 1).

A  $\pm 10\%$  threshold is usually set to 11% below the nominal input voltage, or 4.45V in this example. The threshold is guaranteed to be within the 4.4V to 4.5V band over temperature. To prevent malfunction, the powered system must operate reliably down to 4.4V.

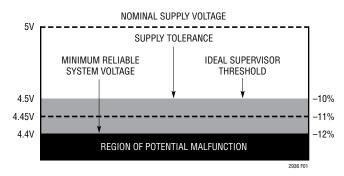


Figure 1. 1% Threshold Accuracy Improves System Reliability



29361

### I<sup>2</sup>C Serial Digital Interface

The LTC2936 communicates with a host (master) using the  $I^2C$  serial bus interface. The Timing Diagram shows the timing relationship of the signals on the bus. The two bus lines, SDA and SCL, must be high when the bus is not in use. External pull-up resistors or current sources are required on these lines.

The LTC2936 is a transmit/receive slave only device. The master device must initiate data transfer on the bus by

generating SCL to allow the transfer. In the event of an OV/UV fault, the LTC2936 can be configured to assert the ALERT output low in order to notify the host.

#### **Slave Address**

The LTC2936 can respond to one of 9 addresses. By connecting the address ASEL0 and ASEL1 inputs to  $V_{DD33}$ , GND, or by floating them, the slave address is determined as shown in the following table. The LTC2936 always responds to the special addresses.

#### LTC2936 Address Look-Up Table

ASELO	0	Hi-Z	1	0	Hi-Z	1	0	Hi-Z	1
ASEL1	0	0	0	Hi-Z	Hi-Z	Hi-Z	1	1	1
7-Bit Address	0x50	0x51	0x52	0x53	0x54	0x55	0x58	0x59	0x5A
8-Bit Address	0xA0	0xA2	0xA4	0xA6	0xA8	0xAA	0xB0	0xB2	0xB4

#### LTC2936 Special Slave Addresses

7-BIT ADDRESS	8-BIT ADDRESS	DESCRIPTION
0x0C	Alert Response Address, Independent of the ASEL pin.	
0x73	0xE6	Global address to which all LTC2936's will respond. Independent of the ASEL pin.

#### **Communication Protocols**

- S START CONDITION
- Sr REPEATED START CONDITION
- Rd READ (BIT VALUE OF 1)
- Wr WRITE (BIT VALUE OF 0)
- A ACKNOWLEDGE
- A NOT ACKNOWLEDGEP STOP CONDITION
- MASTER TO SLAVE
- SLAVE TO MASTER

#### Send Byte Format

1	7	1	1	8	1	1
S	SLAVE ADDRESS	Wr	Α	COMMAND CODE	Α	Р

#### Write Word Format

1	7	1	1	8	1	8	1	8	1	1
S	SLAVE ADDRESS	Wr	А	COMMAND CODE	А	DATA BYTE LOW	А	DATA BYTE HIGH	А	Р

#### **Read Word Format**

1	7	1	1	8	1	1	7	1	1	8	1	8	1	1	_
S	SLAVE ADDRESS	Wr	Α	COMMAND CODE	А	Sr	SLAVE ADDRESS	Rd	А	DATA BYTE LOW	А	DATA BYTE HIGH	Ā	Р	2936 F00



**Register Command Set** 

COMMAND Function	DESCRIPTION	R/W/S (See Note)	DATA LENGTH (BITS)	COMMAND Byte	DEFAULT VALUE
WRITE_PROTECT	Contains lock key code and write lock.	R/W	16	0x00	1010_1010_1010_1000b
GPI_CONFIG	Configure GPI2 and GPI1 assignment, GPIO <i>n</i> mapping and MR internal response.	R/W	16	0x01	X001_0000_X000_0000b
GPI01_CONFIG	Configure GPIO1 type, delay-on-release and mapping to GPIO2, GPIO3.	R/W	16	0x02	X000_0000_0010_1011b
GPIO2_3_CONFIG	Configure GPIO3 type, delay-on-release and mapping to GPIO1 and GPIO2. Configure GPIO2 type, delay-on- release and mapping to GPIO1 and GPIO3.	R/W	16	0x03	0010_1011_0010_1011b
V1_THR	Encode high and low voltage thresholds on channel V1.	R/W	16	0x04	1110_0110_1011_0100b
V2_THR	Encode high and low voltage thresholds on channel V2.	R/W	16	0x05	1000_1001_0110_1000b
V3_THR	Encode high and low voltage thresholds on channel V3.	R/W	16	0x06	0101_1101_0100_0100b
V4_THR	Encode high and low voltage thresholds on channel V4.	R/W	16	0x07	1001_1001_0111_0101b
V5_THR	Encode high and low voltage thresholds on channel V5	R/W	16	0x08	0111_1000_0101_1010b
V6_THR	Encode high and low voltage thresholds on channel V6.	R/W	16	0x09	0101_0111_0011_1111b
V1_CONFIG	Encode comparator range, polarity and GPIO <i>n</i> mapping.	R/W	16	0x0A	XXX0_1100_1000_1001b
V2_CONFIG	Encode comparator range, polarity and GPIO <i>n</i> mapping.	R/W	16	0x0B	XXX0_1100_1000_1001b
V3_CONFIG	Encode comparator range, polarity and GPIO <i>n</i> mapping.	R/W	16	0x0C	XXX0_1100_1000_1001b
V4_CONFIG	Encode comparator range, polarity and GPIO <i>n</i> mapping.	R/W	16	0x0D	XXX0_1101_1000_1001b
V5_CONFIG	Encode comparator range, polarity and GPIO <i>n</i> mapping.	R/W	16	0x0E	XXX0_1101_1000_1001b
V6_CONFIG	Encode comparator range, polarity and GPIO <i>n</i> mapping.	R/W	16	0x0F	XXX0_1101_1000_1001b
HISTORY_WORD	Read the fault history. Read only.	R	16	0x11	NA
PADS	Return the status of the GPI <i>n</i> , GPIO <i>n</i> and CMP <i>n</i> pins.	R	16	0x1A	NA
CLEAR_HISTORY	Clear volatile memory history register. Write only.	S	0	0x1B	NA
STORE_USER	Store volatile memory to EEPROM. Write only.	S	0	0x1C	NA
RESTORE_USER	Restore volatile memory from EEPROM. Write only.	S	0	0x1D	NA
BACKUP_WORD	Read the EEPROM backup of the first fault history. Read only.	R	16	0x1E	NA
STATUS_WORD	Read the fault status. Read only.	R	16	0x1F	NA

**Note:** R = Read, W = Write, S = Send Byte.

### **DETAILED COMMAND REGISTER DESCRIPTIONS**

### WRITE\_PROTECT (Command Byte 0x00)

The WRITE\_PROTECT command provides the ability to prevent any write operations into the volatile memory, if WRITE\_LOCK = 1. KEY may be changed when WRITE\_LOCK = 0, or in the same command that sets WRITE\_LOCK = 1.

When locked, WRITE\_LOCK can only be written to 0 if KEY matches the existing value in memory. For effective protection against false writes, KEY should contain at least one bit set to 1.

Writes to supported commands are ignored when WRITE\_LOCK = 1 or when a GPIn input configured for  $\overline{WP}$  is held low. All commands may be read regardless of the WRITE\_LOCK bit setting.

WRITE	PROTECT	Data	Contents
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BIT(S)	SYMBOL	PURPOSE
b[15:2]	KEY	Must match against programmed combination in order to deactivate write lock. Factory default 10_1010_1010b (0x2AAA).
b[1]	Reserved	Ignore
b[0]	WRITE_LOCK	<ul> <li>0: Unlocked. Writes to volatile memory are permitted.</li> <li>1: Locked. Writing to volatile memory is not permitted. To unlock, set WRITE_LOCK = 0 with the appropriate key. If a GPI<i>n</i> input is configured for WP, and is low, then reading WRITE_PROTECT will always return WRITE_LOCK = 1.</li> <li>Factory default 0.</li> </ul>



### GPI\_CONFIG (Command Byte 0x01)

The GPI\_CONFIG command configures internal response to a manual reset, sets each GPI function, and optionally maps GPI pins configured as Manual Reset (MR) or Auxiliary Comparator (AUXC) to one or more GPIO pins.

#### GPI\_CONFIG Data Contents

BIT(S)	SYMBOL	OPERATION
b[15]	Reserved	Ignore
b[14]	GPI2_MR_RESPONSE	Effective only if the input GPI2 is MR configured. 0: Disable CLEAR_HISTORY response. 1: Enable CLEAR_HISTORY response on falling edge of GPI2. Factory default 0.
b[13:11]	GPI2_CONFIG	<ul> <li>000b: Manual Reset (MR) active low, 15μA pull-up.</li> <li>001b: Reserved.</li> <li>010b: Margin (MARG) active low, 15μA pull-up. Overvoltage and undervoltage faults are inhibited.</li> <li>011b: UV Disable (UVDIS) active low, 15μA pull-up. Undervoltage faults are inhibited.</li> <li>100b: Write Protect (WP).</li> <li>101b: Auxiliary Comparator (AUXC) positive input on GPI2.</li> <li>110b: and 111b: Auxiliary Comparator (AUXC) negative input on GPI2.</li> <li>Factory default 010b.</li> </ul>
b[10]	MAP_GPI2_TO_GPI03	0: GPI2 input is not mapped to GPI03. 1: GPI2 input is mapped to GPI03 if configured as MR or AUXC. Factory default 0.
b[9]	MAP_GPI2_T0_GPI02	0: GPI2 input is not mapped to GPI02. 1: GPI2 input is mapped to GPI02 if configured as MR or AUXC. Factory default 0.
b[8]	MAP_GPI2_TO_GPI01	0: GPI2 input is not mapped to GPI01. 1: GPI2 input is mapped to GPI01 if configured as MR or AUXC. Factory default 0.
b[7]	Reserved	Ignore
b[6]	GPI1_MR_RESPONSE	Effective only if the input GPI1 is MR configured. 0: Disable CLEAR_HISTORY response. 1: Enable CLEAR_HISTORY response on falling edge of GPI1. Factory default 0.
b[5:3]	GPI1_CONFIG	<ul> <li>000b: Manual Reset (MR) active low, 15μA pull-up.</li> <li>001b: Reserved.</li> <li>010b: Margin (MARG) active low, 15μA pull-up. Overvoltage and undervoltage faults are inhibited.</li> <li>011b: UV Disable (UVDIS) active low, 15μA pull-up. Undervoltage faults are inhibited.</li> <li>100b: Write Protect (WP).</li> <li>101b: Auxiliary Comparator (AUXC) positive input on GPI1.</li> <li>110b: and 111b: Auxiliary Comparator (AUXC) negative input on GPI1.</li> <li>Factory default 000b.</li> </ul>
b[2]	MAP_GPI1_TO_GPI03	0: GPI1 input is not mapped to GPI03. 1: GPI1 input is mapped to GPI03 if configured as MR or AUXC. Factory default 0.
b[1]	MAP_GPI1_T0_GPI02	0: GPI1 input is not mapped to GPI02. 1: GPI1 input is mapped to GPI02 if configured as MR or AUXC. Factory default 0.
b[0]	MAP_GPI1_TO_GPI01	0: GPI1 input is not mapped to GPI01. 1: GPI1 input is mapped to GPI01 if configured as MR or AUXC. Factory default 0.





### GPI01\_CONFIG (Command Byte 0x02)

The GPIO1\_CONFIG command configures the GPIO1 mapping, delay-on-release time, output type, and polarity. If GPIO1\_TYPE\_AND\_POLARITY is configured as ALERT (100b or 111b), the output is latched and cleared after the

LTC2936 acknowledges the alert response address (see SMBus protocol), HISTORY\_WORD is read, or a CLEAR\_ HISTORY command is received. Only one GPIO*n* pin should be configured as ALERT. GPIO*n*\_DELAY\_ON\_RELEASE does not apply to a GPIO*n* pin configured as ALERT.

#### WD\_GPI01\_CONFIG Data Contents

BIT(S)	SYMBOL	OPERATION
b[15:8]	Reserved	Ignore
b[7]	MAP_GPI01_T0_GPI03	0: GPI01 input is not mapped to GPI03. 1: GPI01 input is mapped to GPI03. Factory default 0.
b[6]	MAP_GPI01_T0_GPI02	0: GPI01 input is not mapped to GPI02. 1: GPI01 input is mapped to GPI02. Factory default 0.
b[5:3]	GPI01_DELAY_ON_RELEASE	000b: Delay selected is 0.001b: Delay selected is 1.6ms.010b: Delay selected is 6.4ms.011b: Delay selected is 26ms.100b: Delay selected is 51ms.101b: Delay selected is 205ms.110b: Delay selected is 410ms.111b: Delay selected is 1.64s.Factory default 101b (205ms).
b[2:0]	GPI01_TYPE_AND_POLARITY	000b: Active H input.001b: Active L input.010b: Active H open-drain output.011b: Active L open-drain output.100b: Active L open-drain ALERT output.101b: Active H, weak pull-up output.110b: Active L, weak pull-up output.111b: Active L, weak pull-up output.111b: Active L, weak pull-up ALERT output.



### GPI02\_3\_CONFIG (Command Byte 0x03)

The GPIO2\_3\_CONFIG command configures GPIO2 and GPIO3 mapping, delay-on-release time, output type, and polarity. If GPIO2\_TYPE\_AND\_POLARITY is configured as ALERT (100b or 111b), or GPIO3\_TYPE\_AND\_POLARITY is configured as ALERT (100b or 111b), the output is latched,

and is cleared after the LTC2936 acknowledges the alert response address (see SMBus protocol), HISTORY\_WORD is read, or a CLEAR\_HISTORY command is received. Only one GPIO*n* pin should be configured as ALERT. GPIO*n*\_DELAY\_ON\_RELEASE does not apply to a GPIO*n* pin configured as ALERT.

#### GPI02\_3\_CONFIG Data Contents

BIT(S)	SYMBOL	OPERATION
b[15]	MAP_GPI03_T0_GPI02	0: GPI03 is not mapped into GPI02. 1: GPI03 is mapped into GPI02. Factory default 0.
b[14]	MAP_GPI03_T0_GPI01	0: GPIO3 is not mapped into GPIO1. 1: GPIO3 is mapped into GPIO1. Factory default 0.
b[13:11]	GPIO3_DELAY_ON_RELEASE	000b: Delay selected is 0. 001b: Delay selected is 1.6ms. 010b: Delay selected is 6.4ms. 011b: Delay selected is 26ms. 100b: Delay selected is 51ms. 101b: Delay selected is 205ms. 110b: Delay selected is 410ms. 111b: Delay selected is 1.64s. Factory default 101b (205ms).
b[10:8]	GPI03_TYPE_AND_POLARITY	000b: Active H input.         001b: Active L input.         010b: Active H open-drain output.         011b: Active L open-drain output.         100b: Active L open-drain ALERT output.         101b: Active H, weak pull-up output.         110b: Active L, weak pull-up output.         111b: Active L, weak pull-up output.         111b: Active L, weak pull-up ALERT output.         111b: Active L, weak pull-up ALERT output.         Factory default 011b (Active L open-drain output).
b[7]	MAP_GPI02_T0_GPI03	0: GPI02 is not mapped into GPI03. 1: GPI02 is mapped into GPI03. Factory default 0.
b[6]	MAP_GPI02_T0_GPI01	0: GPI02 is not mapped into GPI01. 1: GPI02 is mapped into GPI01. Factory default 0.
b[5:3]	GPI02_DELAY_ON_RELEASE	000b: Delay selected is 0.001b: Delay selected is 1.6ms.010b: Delay selected is 6.4ms.011b: Delay selected is 26ms.100b: Delay selected is 51ms.101b: Delay selected is 205ms.110b: Delay selected is 410ms.111b: Delay selected is 1.64s.Factory default 101b (205ms).
b[2:0]	GPI02_TYPE_AND_POLARITY	000b: Active H input.         001b: Active L input.         010b: Active H open-drain output.         011b: Active L open-drain output.         100b: Active L open-drain ALERT output.         101b: Active L open-drain ALERT output.         101b: Active H, weak pull-up output.         110b: Active L, weak pull-up output.         111b: Active L, weak pull-up ALERT output.         Factory default 011b (Active L open-drain output).





### V1\_THR (Command Byte 0x04), V2\_THR (0x05), V3\_THR (0x06), V4\_THR (0x07),V5\_THR (0x08), V6\_THR (0x09)

The Vn\_THR command allows the user to specify the high and low threshold monitoring voltages on each channel.

#### Vn\_THR Data Contents Channels V1 to V6

BIT(S)	SYMBOL	OPERATION	
b[15:8]	Vn_THR_HI	The COMP <i>n</i> _HI threshold. See the Applications Information section. Factory default settings of 0xE6, 0x89, 0x5D, 0x99, 0x78, 0x57 correspond to 5.5V, 3.64V, 2.76V, 1.98V, 1.65V and 1.32V for channels V1 to V6, respectively.	
b[7:0]	Vn_THR_LO	The COMP <i>n</i> _LO threshold. See the Applications Information section. Factory default settings of 0xB4, 0x68, 0x44, 0x75, 0x5A, 0x3F correspond to 4.5V, 2.98V, 2.26V, 1.62V 1.35V and 1.08V for channels V1 to V6, respectively.	

### V1\_CONFIG (Command Byte 0x0A), V2\_CONFIG (0x0B), V3\_CONFIG (0x0C), V4\_CONFIG (0x0D), V5\_CONFIG (0x0E), V6\_CONFIG (0x0F)

The Vn\_CONFIG command programs V1 through V6 comparator range, polarity and mapping to GPIOn and CMPn.

#### Vn\_CONFIG Data Contents Channels V1 to V6

BIT(S)	SYMBOL	OPERATION
b[15:13]	Reserved	Ignore
b[12]	CMPn_LATCH	0: CMP <i>n</i> output not latched. 1: CMP <i>n</i> output latched. Factory default 0.
b[11]	MAP_COMP <i>n</i> _HI_TO_CMP <i>n</i>	0: High comparator not mapped to CMP <i>n.</i> 1: High comparator mapped to CMP <i>n.</i> Factory default 1.
b[10]	MAP_COMPn_LO_TO_CMPn	0: Low comparator not mapped to CMP <i>n.</i> 1: Low comparator mapped to CMP <i>n.</i> Factory default 1.
b[9:8]	Vn_RANGE	00b: Medium Range. 01b: Low Range. 10b and 11b: Precision Range. Factory defaults are 00b on V1-V3 and 01b on V4-V6.
b[7]	Vn_POL_HI	<ul> <li>Controls polarity of COMPn_HI output reported by STATUS_WORD. See STATUS_WORD description for details.</li> <li>0: Undervoltage. Indicates a fault when the input voltage is below Vn_THR_HI.</li> <li>1: Overvoltage. Indicates a fault when the input voltage is above Vn_THR_HI.</li> <li>Factory default 1.</li> </ul>
b[6]	Vn_POL_LO	Controls polarity of COMP <i>n</i> _LO output reported by STATUS_WORD. See STATUS_WORD description for details. 0: Undervoltage. Indicates a fault when the input voltage is below V <i>n</i> _THR_LO. 1: Overvoltage. Indicates a fault when the input voltage is above V <i>n</i> _THR_LO. Factory default 0.
b[5]	MAP_COMP <i>n</i> _HI_TO_GPIO3	0: High comparator not mapped to GPI03. 1: High comparator mapped to GPI03. Factory default 0.
b[4]	MAP_COMP <i>n</i> _HI_TO_GPI02	0: High comparator not mapped to GPI02. 1: High comparator mapped to GPI02. Factory default 0.



#### Vn\_CONFIG Data Contents Channels V1 to V6

b[3]	MAP_COMP <i>n</i> _HI_TO_GPI01	0: High comparator not mapped to GPI01. 1: High comparator mapped to GPI01. Factory default 1.
b[2]	MAP_COMP <i>n</i> _LO_TO_GPI03	0: Low comparator not mapped to GPI03. 1: Low comparator mapped to GPI03. Factory default 0.
b[1]	MAP_COMP <i>n</i> _LO_TO_GPI02	0: Low comparator not mapped to GPI02. 1: Low comparator mapped to GPI02. Factory default 0.
b[0]	MAP_COMP <i>n</i> _LO_TO_GPI01	0: Low comparator not mapped to GPI01. 1: Low comparator mapped to GPI01. Factory default 1.

### HISTORY\_WORD (Command Byte 0x11)

The HISTORY\_WORD command returns two bytes of information with a summary of the faults since power was applied or HISTORY\_WORD was last cleared. HISTORY\_ WORD is located in volatile memory and is automatically updated each time a fault occurs. HISTORY\_WORD is cleared using the CLEAR\_HISTORY command.

#### **HISTORY\_WORD** Data Contents

BIT(S)	SYMBOL	OPERATION
b[15:13]	Reserved	
b[12]	V6_HI_LATCHED_FAULT	1: Latched V6_HI_FAULT. 0: No fault.
b[11]	V6_LO_LATCHED_FAULT	1: Latched V6_LO_FAULT. 0: No fault.
b[10]	V5_HI_LATCHED_FAULT	1: Latched V5_HI_FAULT. 0: No fault.
b[9]	V5_LO_LATCHED_FAULT	1: Latched V5_LO_FAULT. 0: No fault.
b[8]	V4_HI_LATCHED_FAULT	1: Latched V4_HI_FAULT. 0: No fault.
b[7]	V4_LO_LATCHED_FAULT	1: Latched V4_LO_FAULT. 0: No fault.
b[6]	V3_HI_LATCHED_FAULT	1: Latched V3_HI_FAULT. 0: No fault.
b[5]	V3_LO_LATCHED_FAULT	1: Latched V3_LO_FAULT. 0: No fault.
b[4]	V2_HI_LATCHED_FAULT	1: Latched V2_HI_FAULT. 0: No fault.
b[3]	V2_LO_LATCHED_FAULT	1: Latched V2_LO_FAULT. 0: No fault.
b[2]	V1_HI_LATCHED_FAULT	1: Latched V1_HI_FAULT. 0: No fault.
b[1]	V1_LO_LATCHED_FAULT	1: Latched V1_LO_FAULT. 0: No fault.
b[0]	Reserved	lanore



### PADS (Command Byte 0x1A)

The PADS register returns the status of the GPI*n*, GPIO*n* and CMP*n* pads.

#### PADS Data Contents

BIT(S)	SYMBOL	OPERATION
b[15:11]	Reserved	Ignore
b[10]	GPI2_STATUS	0: GPI2 pin is logic low. 1: GPI2 pin is logic high.
b[9]	GPI1_STATUS	0: GPI1 pin is logic low. 1: GPI1 pin is logic high.
b[8]	GPIO3_STATUS	0: GPIO3 pin is logic low. 1: GPIO3 pin is logic high.
b[7]	GPI02_STATUS	0: GPIO2 pin is logic low. 1: GPIO2 pin is logic high.
b[6]	GPIO1_STATUS	0: GPI01 pin is logic low. 1: GPI01 pin is logic high.
b[5]	CMP6_STATUS	0: CMP6 pin is logic low. 1: CMP6 pin is logic high.
b[4]	CMP5_STATUS	0: CMP5 pin is logic low. 1: CMP5 pin is logic high.
b[3]	CMP4_STATUS	0: CMP4 pin is logic low. 1: CMP4 pin is logic high.
b[2]	CMP3_STATUS	0: CMP3 pin is logic low. 1: CMP3 pin is logic high.
b[1]	CMP2_STATUS	0: CMP2 pin is logic low. 1: CMP2 pin is logic high.
b[0]	CMP1_STATUS	0: CMP1 pin is logic low. 1: CMP1 pin is logic high.

### CLEAR\_HISTORY (Command Byte 0x1B)

The CLEAR\_HISTORY command clears all the faults logged in the volatile HISTORY\_WORD register. A manual reset performs the same operation if GPI $n_MR_RESPONSE = 1$ . Clearing HISTORY\_WORD does not affect the STATUS\_ WORD content. Processing of the CLEAR\_HISTORY command typically takes less than 10ms, and the part will not acknowledge other I<sup>2</sup>C operations during that time.

### STORE\_USER (Command Byte 0x1C) RESTORE\_USER (Command Byte 0x1D)

The STORE\_USER and RESTORE\_USER commands access nonvolatile EEPROM memory. Once a command is

stored in EEPROM using STORE\_USER, it will be restored to volatile operating memory with the RESTORE\_USER command or when the part powers up.

### BACKUP\_WORD (Command Byte 0x1E)

After the first fault occurs, HISTORY\_WORD is written to EEPROM for backup. Any subsequent BACKUP\_WORD write following a fault is inhibited until the CLEAR\_HISTORY command is issued. BACKUP\_WORD can be retrieved by sending a RESTORE\_USER command followed by a BACKUP\_WORD read. BACKUP\_WORD can be cleared in EEPROM by sending a CLEAR\_HISTORY command followed by a STORE\_USER command.



### STATUS\_WORD (Command Byte 0x1F)

The STATUS\_WORD command returns two bytes of information with a summary of the current faults. The STATUS\_WORD content is read directly from the comparators and is a snapshot of the current state.

STATUS\_WORD faults may be disabled by setting GPI1\_ CONFIG = 010b (MARG), GPI1\_CONFIG = 011b (UVDIS), GPI2\_CONFIG = 010b (MARG) or GPI2\_CONFIG = 011b (UVDIS) and asserting the appropriate GPI*n* pin.

#### STATUS\_WORD Data Contents

BIT(S)	SYMBOL	OPERATION
b[15:13]	Reserved	Ignore
b[12]	V6_HI_FAULT	V6_POL_HI = 1 (default). 1: Fault (V6 greater than V6_THR_HI). 0: No fault (V6 less than V6_THR_HI).
		V6_POL_HI = 0. 1: Fault (V6 less than V6_THR_HI). 0: No fault (V6 greater than V6_THR_HI).
b[11]	V6_LO_FAULT	V6_POL_LO = 1. 1: Fault (V6 greater than V6_THR_LO). 0: No fault (V6 less than V6_THR_LO).
		V6_POL_LO = 0 (default). 1: Fault (V6 less than V6_THR_LO). 0: No fault (V6 greater than V6_THR_LO).
b[10]	V5_HI_FAULT	V5_POL_HI = 1 (default). 1: Fault (V5 greater than V5_THR_HI). 0: No fault (V5 less than V5_THR_HI).
		V5_POL_HI = 0. 1: Fault (V5 less than V5_THR_HI). 0: No fault (V5 greater than V5_THR_HI).
b[9]	V5_L0_FAULT	V5_POL_LO = 1. 1: Fault (V5 greater than V5_THR_LO). 0: No fault (V5 less than V5_THR_LO).
		V5_POL_LO = 0 (default). 1: Fault (V5 less than V5_THR_LO). 0: No fault (V5 greater than V5_THR_LO).
b[8]	V4_HI_FAULT	V4_POL_HI = 1 (default). 1: Fault (V4 greater than V4_THR_HI). 0: No fault (V4 less than V4_THR_HI).
		V4_POL_HI = 0. 1: Fault (V4 less than V4_THR_HI). 0: No fault (V4 greater than V4_THR_HI).
b[7]	V4_LO_FAULT	V4_POL_LO = 1. 1: Fault (V4 greater than V4_THR_LO). 0: No fault (V4 less than V4_THR_LO).
		V4_POL_LO = 0 (default). 1: Fault (V4 less than V4_THR_LO). 0: No fault (V4 greater than V4_THR_LO).



#### STATUS\_WORD Data Contents

b[6]	V3_HI_FAULT	V3_POL_HI = 1 (default). 1: Fault (V3 greater than V3_THR_HI). 0: No fault (V3 less than V3_THR_HI).
		V3_POL_HI = 0. 1: Fault (V3 less than V3_THR_HI). 0: No fault (V3 greater than V3_THR_HI).
b[5]	V3_LO_FAULT	V3_POL_LO = 1. 1: Fault (V3 greater than V3_THR_LO). 0: No fault (V3 less than V3_THR_LO).
		V3_POL_LO = 0 (default). 1: Fault (V3 less than V3_THR_LO). 0: No fault (V3 greater than V3_THR_LO).
b[4]	V2_HI_FAULT	V2_POL_HI = 1 (default). 1: Fault (V2 greater than V2_THR_HI). 0: No fault (V2 less than V2_THR_HI).
		V2_POL_HI = 0. 1: Fault (V2 less than V2_THR_HI). 0: No fault (V2 greater than V2_THR_HI).
b[3]	V2_LO_FAULT	V2_POL_LO = 1. 1: Fault (V2 greater than V2_THR_LO). 0: No fault (V2 less than V2_THR_LO).
		V2_POL_LO = 0 (default). 1: Fault (V2 less than V2_THR_LO). 0: No fault (V2 greater than V2_THR_LO).
b[2]	V1_HI_FAULT	V1_POL_HI = 1 (default). 1: Fault (V1 greater than V1_THR_HI). 0: No fault (V1 less than V1_THR_HI).
		V1_POL_HI = 0. 1: Fault (V1 less than V1_THR_HI). 0: No fault (V1 greater than V1_THR_HI).
b[1]	V1_LO_FAULT	V1_POL_LO = 1. 1: Fault (V1 greater than V1_THR_LO). 0: No fault (V1 less than V1_THR_LO).
		V1_POL_LO = 0 (default). 1: Fault (V1 less than V1_THR_LO). 0: No fault (V1 greater than V1_THR_LO).
b[0]	Reserved	Ignore



<sup>2936f</sup>

### **Power Supply**

The LTC2936 is powered from the V<sub>PWR</sub> input and generates a regulated 3.3V supply on the V<sub>DD33</sub>. A 100nF external capacitor from V<sub>PWR</sub> to GND is required in order to decouple any supply noise. A 100nF external capacitor from V<sub>DD33</sub> to GND is required to properly compensate the internal voltage regulator.

To power the LTC2936 directly from an external 3.3V power supply, connect the  $V_{PWR}$  and  $V_{DD33}$  pins together and connect them to the external 3.3V supply. This mode of operation is useful for reducing power dissipation.

### **Power-Up Condition**

When power is applied, the part turns on and the EEPROM contents are loaded into the volatile operating memory. This operation typically takes less than  $200\mu s$ .

### Voltage Threshold Programming

The medium range is based on a full scale of 0.9V to 6V. The 8-bit programming step size is 20mV. On the medium range, threshold accuracy below 1V and above 5.8V is not specified, but the thresholds are reachable.

The command byte for the voltage threshold can be calculated for the medium range with the following equation:

Command Byte = ROUND  $[50 \bullet (V_{TH} - 0.9)]$ 

The low range is based on a full scale of 0.45V to 3V. The 8-bit programming step size is 10mV. On the low range, threshold accuracy below 0.5V is not specified, but the thresholds are reachable.

The command byte for the voltage threshold can be calculated for the low range with the following equation:

Command Byte = ROUND  $[100 \bullet (V_{TH} - 0.45)]$ 

The precision range is based on a full scale of 0.18V to 1.2V. The 8-bit programming step size is 4mV. On the low range, threshold accuracy below 0.2V is not specified, but the thresholds are reachable.

The command byte for the voltage threshold can be calculated for the V2 to V6 precision range with the following equation:

Command Byte = ROUND [250 •  $(V_{TH} - 0.18)$ ]

### **Unused Channels**

The user must connect all unused channel inputs to ground, program their configuration words (V $n_CONFIG$ ) to 0x01C0, and program their thresholds (V $n_THR$ ) to 0x0000 in order to avoid false faults.

### **Auxiliary Comparators**

Two additional auxiliary comparators can be connected to the general purpose inputs with either their inverting or their noninverting input while the other input internally connects to a 0.5V reference voltage. These low offset, low drift comparators can be used for additional monitoring purposes.

If the tap point on an external resistive divider from an external voltage,  $V_{TRIP}$ , to GND (see Figure 2) connects to the auxiliary comparator input, the trip voltage is:

$$V_{\text{TRIP}} = 0.5 \text{V} \cdot \left(1 + \frac{\text{R1}}{\text{R2}}\right)$$

In a negative voltage application (also shown in Figure 2) the resistive divider is connected between the negative voltage being sensed and  $V_{DD33}$ , and the trip voltage is:

$$V_{\text{TRIP}} = 0.5 \text{V} - 2.8 \text{V} \bullet \left(\frac{\text{R3}}{\text{R4}}\right)$$

The minimum value for R4 is limited by the  $V_{\text{DD33}}\xspace$  current sourcing capability at:

$$\frac{3.3V - 0.5V}{1mA} = 2.8k\Omega$$

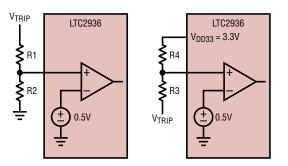


Figure 2. Auxiliary Comparator Usage



29361

### **Manual Reset**

When a GPI*n* pin is configured as  $\overline{MR}$ , the input is active low. If GPI*n*\_MR\_RESPONSE = 1, the HISTORY\_WORD register is cleared when  $\overline{MR}$  is pulled low. An internal 15µA current source pulls  $\overline{MR}$  to V<sub>DD33</sub>. The  $\overline{MR}$  input can also be mapped to a GPIO pin and combined with COMP*n*\_HI and COMP*n*\_LO faults to generate a system reset signal.

### UV Disable

When a GPI*n* pin is configured as  $\overline{\text{UVDIS}}$ , the input is active low. When  $\overline{\text{UVDIS}}$  is grounded, the LTC2936 does not respond to UV type faults. This feature is useful when power cycling the monitored supply. An internal 15µA current source pulls  $\overline{\text{UVDIS}}$  to  $V_{\text{DD33}}$ .

### Margin

When a GPI*n* pin is configured as  $\overline{MARG}$ , the input is active low. When  $\overline{MARG}$  is grounded, the LTC2936 does not respond to any OV or UV faults. This feature is useful when margining the monitored supply. An internal 15µA current source pulls  $\overline{MARG}$  to  $V_{DD33}$ .

### Outputs

The GPIO*n* and CMP*n* outputs are open-drain, with an internal  $15\mu$ A current source pulling to V<sub>DD33</sub> (optional on the GPIO*n* outputs) and can tolerate a pull-up voltage up to 14V.

All faults, GPI*n*, or other GPIO*n* inputs mapped to a GPIO*n* output are combined with a logical OR function.

The GPIO*n* pins have programmable delay-on-release timing. The GPIO*n* pin asserts its active state immediately and de-asserts after the delay-on-release time has elapsed. Any fault causing a GPIO*n* pin to assert while its delay-on-release timer is active will reset the delay-on-release timer.

When a GPIO*n* indicates an alert, the alert may be cleared using the standard SMBus Alert Response Address (ARA) protocol. Alerts may also be cleared by reading (or clearing) HISTORY\_WORD unless the condition causing the alert persists.

The CMP*n* outputs can be configured as non-latching (default) or latching. Latched CMP*n* outputs can be reset

by asserting  $\overline{\text{MR}}$  low or by issuing a CLEAR\_HISTORY command. The CMP*n* outputs are active low.

### Write Protect Features

When the WRITE\_LOCK bit is set high, or a GPI*n* pin configured as  $\overline{WP}$  is pulled low, all I<sup>2</sup>C write word commands are ignored. This feature protects against accidental writing. The lock bit may still be written when the device is write-protected if the provided value for KEY matches the value in memory.

### EEPROM

The user may save and restore configuration data to the operating memory registers at any time with STORE\_USER and RESTORE\_USER commands. Upon power-up, userstored data is automatically loaded into the operating memory. The part ignores I<sup>2</sup>C commands while performing EEPROM transactions.

Nondestructive operation above  $T_A = 85^{\circ}C$  is possible, but may result in a slight degradation of the retention characteristics. The degradation in EEPROM retention for temperatures exceeding 85°C can be approximated by calculating the acceleration factor:

$$\mathsf{AF} = \mathsf{e}^{\left[\left(\frac{\mathsf{E}_{\mathsf{a}}}{\mathsf{k}}\right) \cdot \left(\frac{1}{\mathsf{T}_{\mathsf{USE}} + 273} - \frac{1}{\mathsf{T}_{\mathsf{STRESS}} + 273}\right)\right]}$$

where:

AF = acceleration factor

 $E_a = activation energy = 1.5eV$ 

k = 8.625 • 10<sup>-5</sup> eV/°K

 $T_{USE} = 85$  °C maximum specified junction temperature  $T_{STRESS} = actual junction temperature °C$ 

Example: calculate effect on retention when operating at a junction temperature of 95°C for 10 hours.

$$T_{STBESS} = 95^{\circ}C, T_{USE} = 85^{\circ}C, AF = 3.74$$

So the overall retention of the EEPROM was degraded by 37.4 hours as a result of operation at a junction temperature of 95°C for 10 hours. Note that the effect of this overstress is negligible when compared to the overall EEPROM retention rating of 10 years (87,600 hours) at a temperature of 85°C.



### **Negative Supply Power Monitor**

Figure 3 illustrates how to configure the LTC2936 to monitor a negative supply rail. Assume the need to monitor the following supply rails: 1.5V, 3.3V, 5V and -5V, within a  $\pm 5\%$  system specification.

Channels V1 and V2 are set to medium range, channel V3 is set to low range, channel V4 is set to precision range, and channels V5 and V6 are not used.

Select medium range for V1 and V2 (1V to 6V):

V1\_THR\_HI = ROUND[50 • (5 • 1.06 - 0.9)] = 220 V1\_THR\_LO = ROUND[50 • (5 • 0.94 - 0.9)] = 190 V2 THR HI = ROUND[50 • (3.3 • 1.06 - 0.9)] = 130

V2\_THR\_L0 = ROUND[50 • (3.3 • 0.94 - 0.9)] = 110

Select low range for V3 (0.5V to 3V):

V3\_THR\_HI = ROUND[100 • (1.5 • 1.06 -0.45)] = 114

V3\_THR\_LO = ROUND[100 • (1.5 • 0.94 -0.45)] = 96

To monitor -5V, use an external resistive divider connected between V<sub>DD33</sub> and the negative rail. The voltage at V<sub>DD33</sub> is 3.3V. In order to minimize the error introduced by the leakage current into the V4 input pin, the output of this divider is targeted to lie within the precision voltage range (0.2V to 1.2V). The OV and UV thresholds for the -5V rail are calculated as follows:

$$V5_{MIN} = \frac{(3.3 \cdot R1) - 1.05 \cdot (5 \cdot R2)}{R1 + R2} > 0.2V$$
$$V5_{MAX} = \frac{(3.3 \cdot R1) - 0.95 \cdot (5 \cdot R2)}{R1 + R2} < 1.2V$$

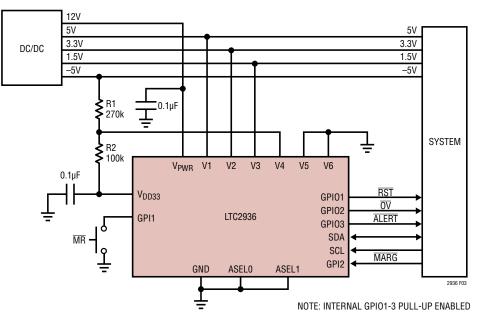


Figure 3. Negative Supply Power Monitor



 $R1 = 270k \pm 0.1\%$  and  $R2 = 100k \pm 0.1\%$  satisfy the previous relationships. The programming codes can be calculated as shown in the following equations:

 $V4_{MIN} =$ 

$$\frac{(3.3 \bullet 0.98) \bullet (270 \bullet 0.999) - (1.05 \bullet 5) \bullet (100 \bullet 1.001)}{(270 \bullet 0.999) + (100 \bullet 1.001)}$$
  
= 0.938V

 $V4_{MAX} = \frac{(3.3 \cdot 1.02) \cdot (270 \cdot 1.001) - (0.95 \cdot 5) \cdot (100 \cdot 0.999)}{(270 \cdot 1.001) + (100 \cdot 0.999)}$ = 1.176V V4\_THR\_HI = ROUND[250 • (0.938 • 0.99 - 0.18)] = 187 V4\_THR\_LO = ROUND[250 • (1.176 • 1.01 - 0.18)] = 252

The normal polarities of the OV and UV comparators need to be swapped, since a drop of the negative supply below its specified absolute value increases  $V4_{MAX}$  beyond its encoded threshold. An increase of the negative supply above its specified absolute value decreases  $V4_{MIN}$  below its encoded threshold.

The GPIO*n* outputs are programmed as  $\overline{\text{RST}}$  (active low system reset),  $\overline{\text{OV}}$  (active low system OV) and  $\overline{\text{ALERT}}$  (active low  $\overline{\text{ALERT}}$ , see SMBus specification). The UV comparators are mapped to GPIO1 and GPIO3. The OV comparators are mapped to GPIO2 and GPIO3. The GPI1 input is configured as  $\overline{\text{MR}}$  (manual reset) and is mapped to GPIO1. The GPI2 input is configured as  $\overline{\text{MARG}}$  (margin testing) allowing the system to disable OV and UV faults during margin testing.



### Five Supply Power-Up Sequencer

Figure 4 illustrates how to use the LTC2936 CMPn outputs to enable DC/DC converters sequentially, at power-up. The system is powered by a 12V source, which is also monitored.

The system starts-up when the pushbutton is pressed and the LTC2950-1 takes the RUN pin of the LTM4600 high. This forces the LTM4600 to generate 5V, which also supplies the other 4 DC/DC converters.

The LTC2936 is configured to monitor 5V on V1, 3.3V on V2, 2.5V on V3, -5V on V4, 1.8V on V5 and 12V on V6. When the programmed threshold is reached on V1, CMP1

pulls high, which enables the 3.3V converter. When the programmed threshold is reached on V2, CMP2 pulls high, which enables the 2.5V converter. When all converters have been enabled and power is good, CMP5 pulls high. GPIO1 is configured to pull high 6.4ms after CMP5.

If the KILL input of the LTC2950-1 is not forced high within 512ms of initial power-up, EN pulls low and the LTM4600 is powered down.

In the event that the external 12V supply drops below its programmed threshold, CMP6 and GPI02 will pull low after 1.6ms. The LTC2950-1 then receives a logic low on the  $\overline{\text{KILL}}$  input, which powers down the LTM4600 and the sequencing circuit.

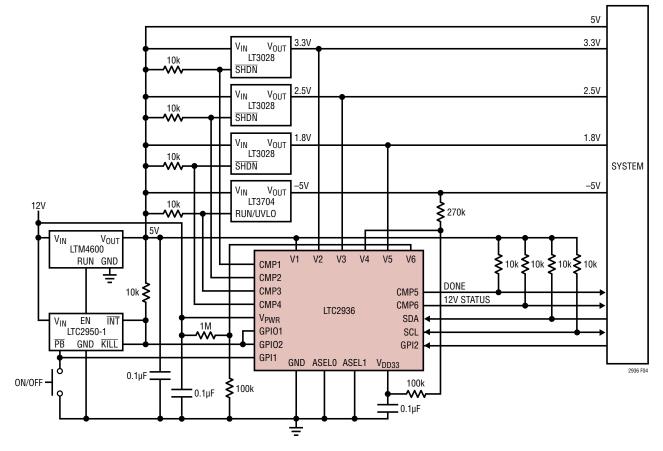


Figure 4. Five Supply Power-Up Sequencer



29361

### Seven Power Supply Monitor

Figure 5 illustrates how to use the LTC2936 auxiliary comparators to expand power supply monitoring to seven channels. The system is powered by a 5V source, which is also monitored. The 9V rail can be monitored, in addition to the six input channels (5V, 3.3V, 2.5V, 1.8V, 1.5V and 24V), using an external resistive divider which feeds the OV and UV tap voltages to the auxiliary comparators on inputs GPI1 and GPI2.

Since the auxiliary comparators' thresholds are fixed at  $0.5V \pm 10mV$ , to monitor a 9V  $\pm 10\%$  power supply, the following equations apply:

R2+R3	0.51V
R1+R2+R3	0.9•9V
R3	0.49V
R1+R2+R3	1.1•9V

For R3 = 8.87k, the equations yield: R2 = 2.4k and R1 = 168k.

The GPI1 comparator monitors the UV limit and is programmed for negative polarity. The GPI2 comparator monitors the OV limit and is programmed for positive polarity.

A second resistive divider is used to divide the 24V rail voltage down to 1.08V, in order to use the low leakage, low range of the V6 channel.

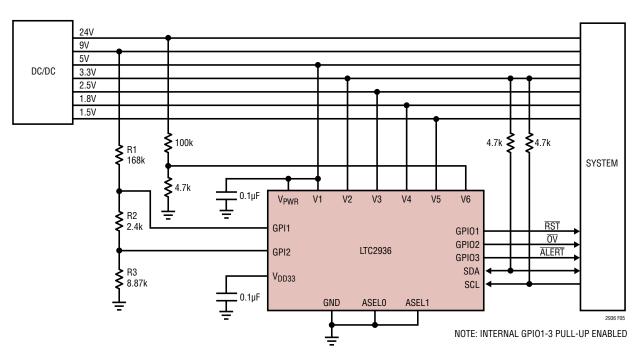
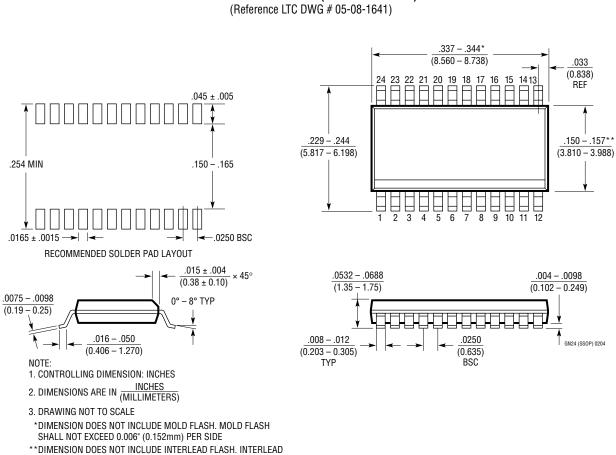


Figure 5. Seven Power Supply Monitor



### PACKAGE DESCRIPTION

Please refer to http://www.linear.com/designtools/packaging/ for the most recent package drawings.



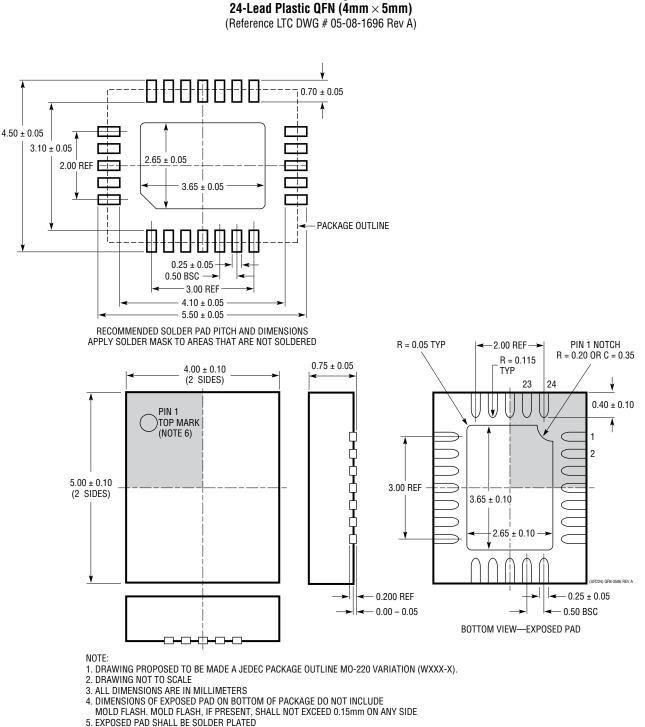
GN Package 24-Lead Plastic SSOP (Narrow .150 Inch)

FLASH SHALL NOT EXCEED 0.010" (0.254mm) PER SIDE



### PACKAGE DESCRIPTION

Please refer to http://www.linear.com/designtools/packaging/ for the most recent package drawings.



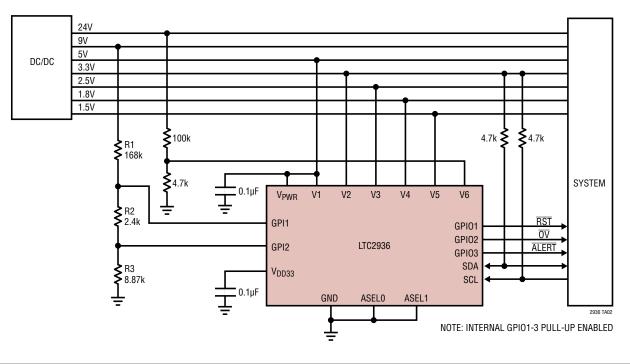
**UFD** Package

- 6. SHADED AREA IS ONLY A REFERENCE FOR PIN 1 LOCATION
  - ON THE TOP AND BOTTOM OF PACKAGE





# TYPICAL APPLICATION



**Seven Power Supply Monitor** 

# **RELATED PARTS**

PART NUMBER	DESCRIPTION	COMMENTS
LTC2908	Precision Six-Input Supply Monitor	Reset: $V_{CC} = 0.5V$ , ±1.5% Accuracy Overtemperature, Internal $V_{CC}$ Auto Select
LTC2910	Octal Positive/Negative Supply Monitor	8 Adjustable Inputs (0.5V), ±1.5% Accuracy, Input Glitch Rejection, Pin-Selectable Input Polarity
LTC2930	Configurable Six-Supply Monitor with Adjustable Reset Timer, Manual Reset	16 Selectable Thresholds
LTC2931	Configurable Six-Supply Monitor with Adjustable Reset and Watchdog Timers	16 Selectable Thresholds, Threshold Tolerance, Separate Voltage Monitor Outputs
LTC2932	Configurable Six-Supply Monitor with Adjustable Reset Timer and Supply Tolerance	16 Selectable Thresholds, Reset Timer, Separate Voltage Monitor Outputs
LTC2933	Programmable Hex Voltage Supervisor with EEPROM	256 Programmable Thresholds, EEPROM, I <sup>2</sup> C Interface
LTC2938	Configurable Four-Supply Monitor with Processor Supervisory Functions	16 Selectable Thresholds, Adjustable Reset Timer, Watchdog Timeout, Watchdog Status Output
LTC2939	Configurable Six-Supply Monitor with Processor Supervisory Functions	16 Selectable Thresholds, Adjustable Reset Timer, Watchdog Timeout, Watchdog Status Output
LTC2977	8-Channel PMBus Power System Manager	0.25% TUE 16-Bit ADC, Voltage/Temperature Monitoring and Supervision
LTC2974	4-Channel PMBus Power System Manager	0.25% TUE 16-Bit ADC, Voltage/Current/Temperature Monitoring and Supervision
LTM2987	16-Channel µModule PMBus Power System Manager	0.25% TUE 16-Bit ADC, Voltage/Temperature Monitoring and Supervision
LTC2970	Dual I <sup>2</sup> C Power Supply Monitor and Margining Controller	Monitors Voltage and Current on Two Power Supplies. Margins to 0.5% Accuracy

